NSN 5961-01-465-4769

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-465-4769 **Inclosure Material:** Glass **Overall Length:** Between 1.000 inches and 1.500 inches Overall Diameter: Between 0.055 inches and 0.090 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 5.049 regulator voltage and 5.151 regulator voltage **Current Rating Per Characteristic:** 5.10 microamperes emitter current, dc **Power Rating Per Characteristic:** 500.0 milliwatts forward power dissipation, dc preset **Test Data Document:** 81349-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 pin **Specification Data:** 81349-mil-s-19500/127m government specification Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: